

X2G100ND06P1

HIGH POWER NPT Low loss TYPE 2-PACK IGBT MODULE

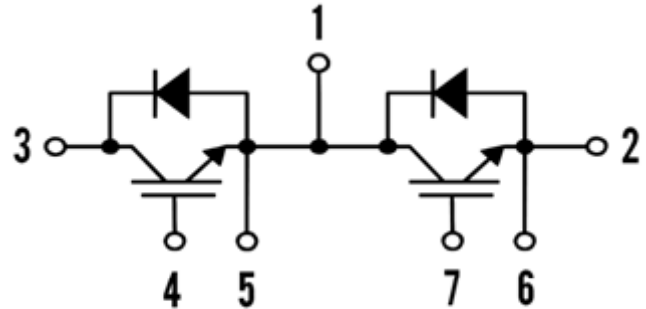


600V
100A

PACKAGE : M1

■ CIRCUIT DIAGRAM

PRELIMINARY



■ FEATURES

- Non Punch Through (NPT) Technology
- Fast & soft inverse CAL diodes
- 10us short circuit capability
- Positive $V_{CE(on)}$ temperature coefficient
- Industry standard package

■ APPLICATIONS

- High power inverter
- Switched mode power supplies (SMPS)
- UPS
- Electrical welding machine

■ ABSOLUTE MAXIMUM RATINGS

$T_c=25^{\circ}\text{C}$, unless otherwise specified

Symbol	Parameter	Conditions	Ratings	Unit
V_{CES}	Collector-emitter voltage	-	600	V
I_C	DC-collector current	$T_c = 25^{\circ}\text{C}$	130	A
		$T_c = 70^{\circ}\text{C}$	100	A
I_{CRM}	Repetitive peak collector current	1ms	200	A
V_{GES}	Gate-emitter peak voltage	-	± 20	V
I_F	Diode continuous forward current	-	100	A
I_{FRM}	Diode repetitive peak forward current	-	200	A
$T_{vj,max}$	Maximum junction temperature	-	-40 ~ 150	$^{\circ}\text{C}$
$T_{vj,op}$	Operating temperature range	-	-40 ~ 125	$^{\circ}\text{C}$
T_{stg}	Storage temperature range	-	-40 ~ 125	$^{\circ}\text{C}$
V_{ISOL}	Insulation test voltage	50Hz, t=1ms	2.5	kV
M_s	Mounting screw torque	M6	3.0 ~ 6.0	N.m
M_t	Mounting terminals screw torque	M5	2.5 ~ 5.0	N.m

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PRELIMINARY

ELECTRICAL CHARACTERISTICS OF IGBT

$T_J=25^\circ\text{C}$ unless otherwise specified

Symbol	Parameter	Min	Typ	Max	Unit	Conditions
$V_{CE(Sat)}$	C-E saturation voltage	-	2.1	-	V	$I_C = 100A, V_{GE} = 15V, T_{vj} = 25^\circ\text{C}$
		-	2.3	-	V	$I_C = 100A, V_{GE} = 15V, T_{vj} = 125^\circ\text{C}$
$V_{GE(th)}$	G-E threshold voltage	4.5	5.5	6.5	V	$I_C = 1mA, V_{CE} = V_{GE}$
I_{CES}	Zero gate voltage collector current	-	-	500	μA	$V_{GE} = 0V, V_{CE} = 600V$
I_{GES}	G-E leakage current	-	-	0.4	μA	$V_{GE} = \pm 20V$
R_{Gint}	Internal gate resistance	-	-	-	Ω	-
C_{ies}	Input capacitance	-	4.3	-	nF	$V_{GE} = 0V, f = 1\text{MHz}, V_{CE} = 25V$
C_{oes}	Output capacitance	-	0.5	-		
C_{res}	Reverse transfer capacitance	-	0.4	-		
Q_g	Total gate charge	-	tbd	-	μC	$V_{GE} = \pm 15V$
$t_{d(on)}$	Turn-on delay time	-	95	-	ns	$V_{CE} = 300V,$ $I_C = 100A,$ $V_{GE} = \pm 15V,$ $R_G = 2.2\Omega,$ $T_{vj} = 125^\circ\text{C}$
t_r	Turn-on rise time	-	30	-		
$t_{d(off)}$	Turn-off delay time	-	200	-		
t_f	Turn-off fall time	-	35	-		
E_{ON}	Turn-on Energy loss	-	1.0	-	mJ	
E_{OFF}	Turn-off Energy loss	-	2.9	-		

ELECTRICAL CHARACTERISTICS OF FRD

$T_J=25^\circ\text{C}$ unless otherwise specified

Symbol	Parameter	Min	Typ	Max	Unit	Conditions
V_F	Diode Forward Voltage Drop	-	1.4	-	V	$T_{vj} = 25^\circ\text{C}$
		-	1.35	-		$T_{vj} = 125^\circ\text{C}$
I_{rr}	Peak Reverse Recovery Current	-	67	-	A	$I_F = 100A,$ $V_{CE} = 600V$ $T_{vj} = 125^\circ\text{C}$
Q_{rr}	Diode Recovery Charge	-	14	-	μC	

THERMAL AND MECHANICAL CHARACTERISTICS

$T_J=25^\circ\text{C}$ unless otherwise specified

Symbol	Parameter	Min	Typ	Max	Unit	Condition
$R_{th(j-c)}$	Junction-to-Case (IGBT Part, Per 1/2 Module)	-	0.28	-	K/W	
$R_{th(j-c)}$	Junction-to-Case (FRD Part, Per 1/2 Module)	-	0.78	-	K/W	
$R_{th(c-f)}$	Case-to-Heat Sink (With Thermal Compound)	-	0.05	-	K/W	
Weight	Module		180		g	

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PERFORMANCE CURVES (I)

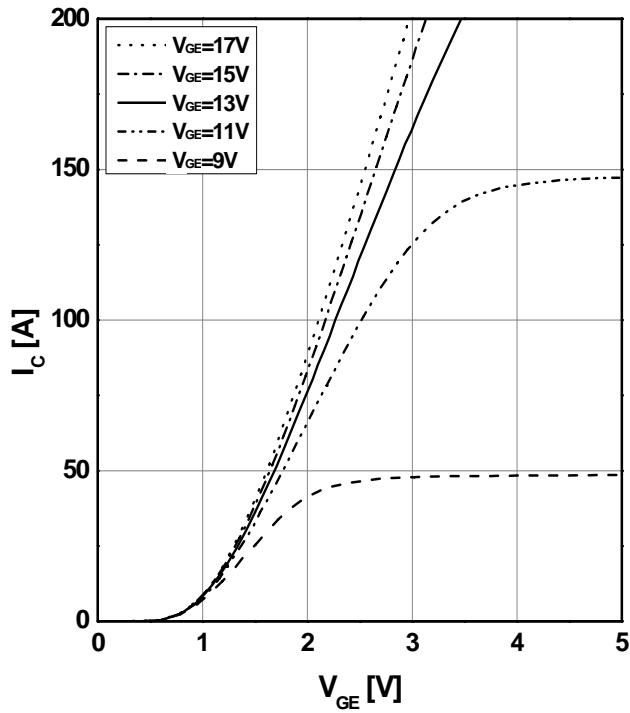


Fig1. Typical Output Characteristics

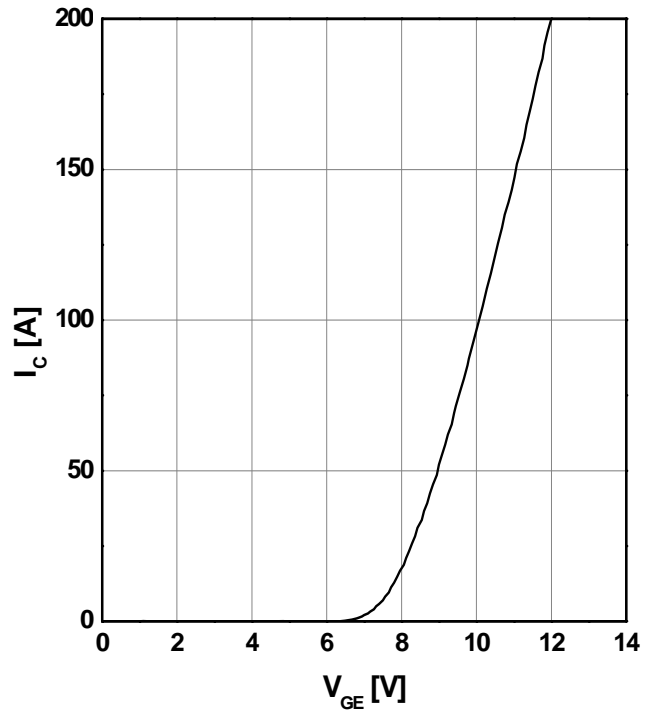


Fig2. Transfer Characteristics

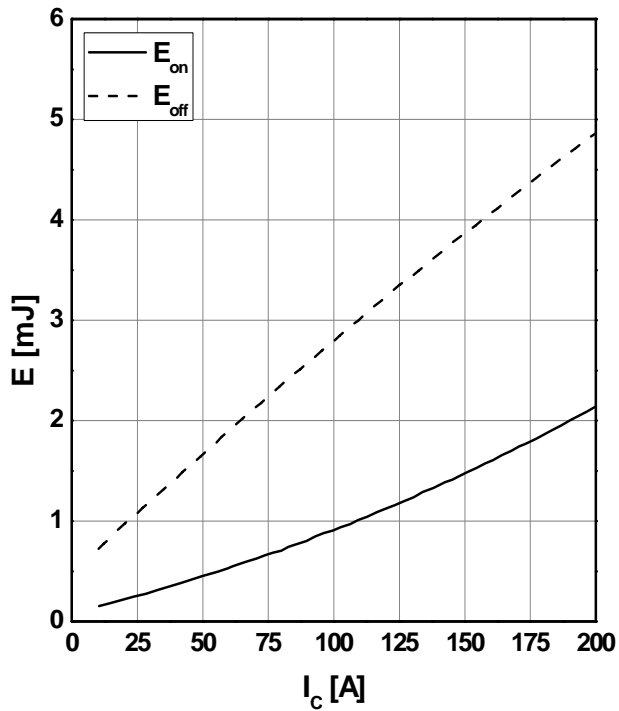


Fig3. Energy Loss vs. I_c

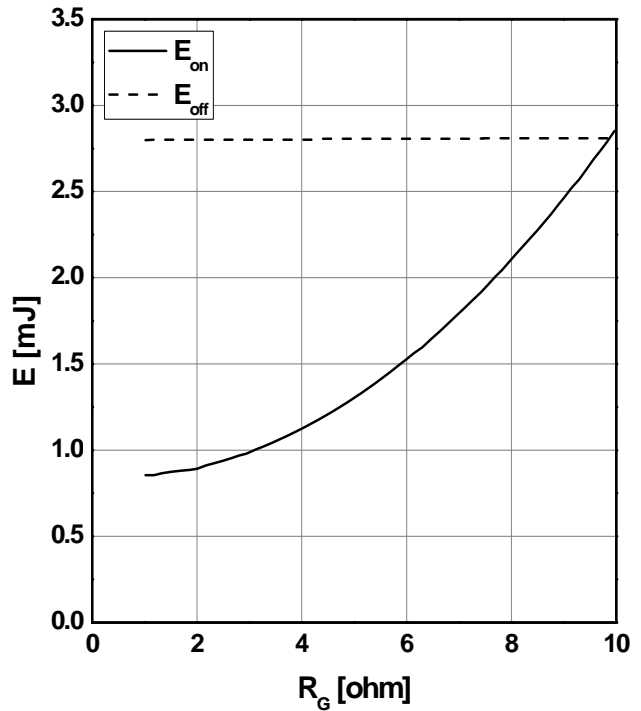


Fig4. Energy Loss vs. R_G

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PERFORMANCE CURVES (II)

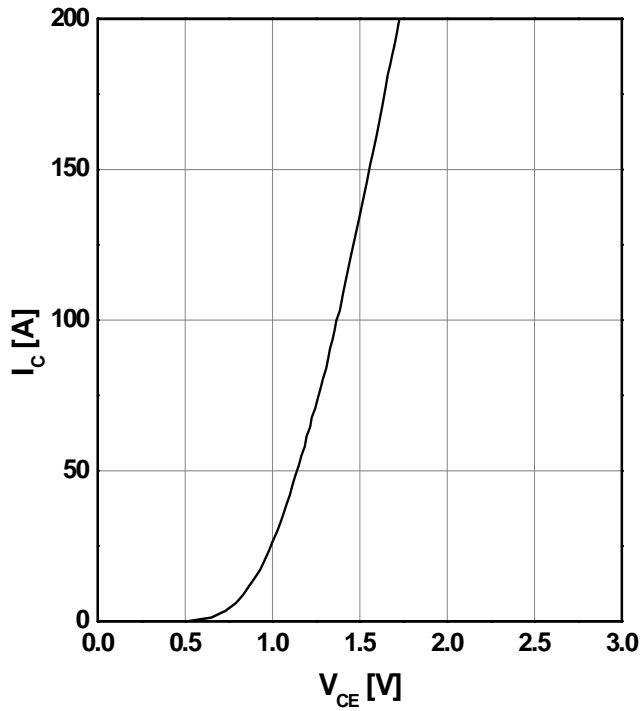


Fig5. DIODE Forward Characteristic

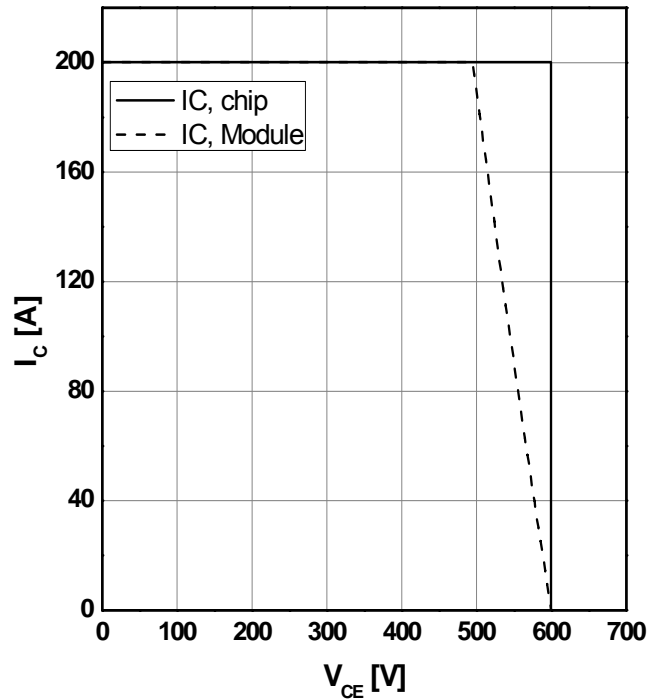


Fig6. Reverse Bias SOA ($T_{vj} = 125^{\circ}\text{C}$)

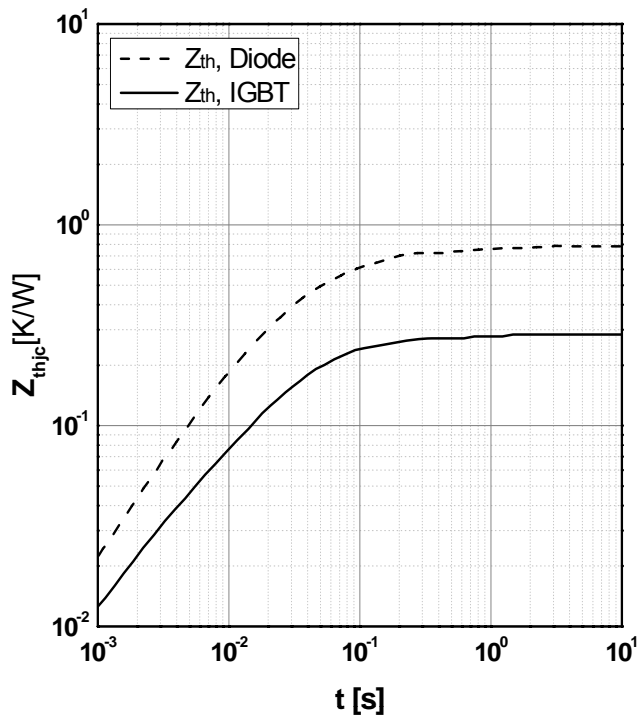


Fig7. Transient Thermal

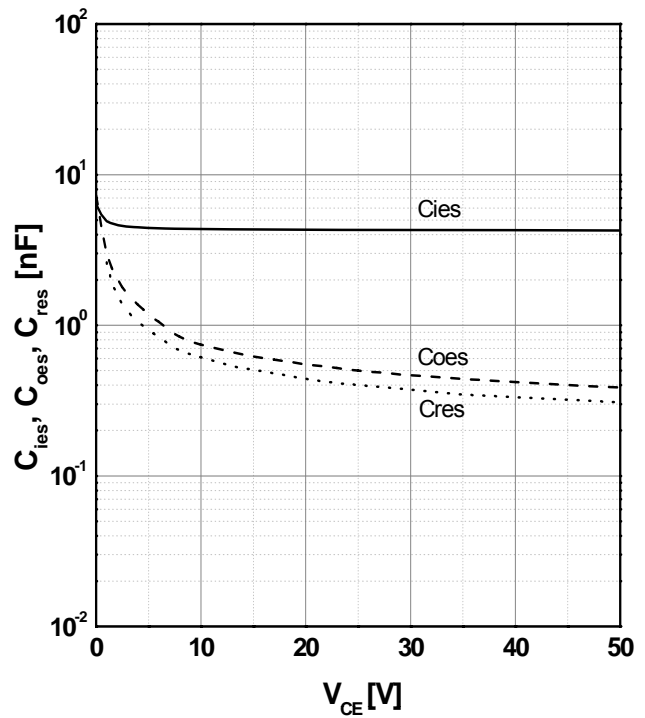


Fig8. Typ. Capacitance

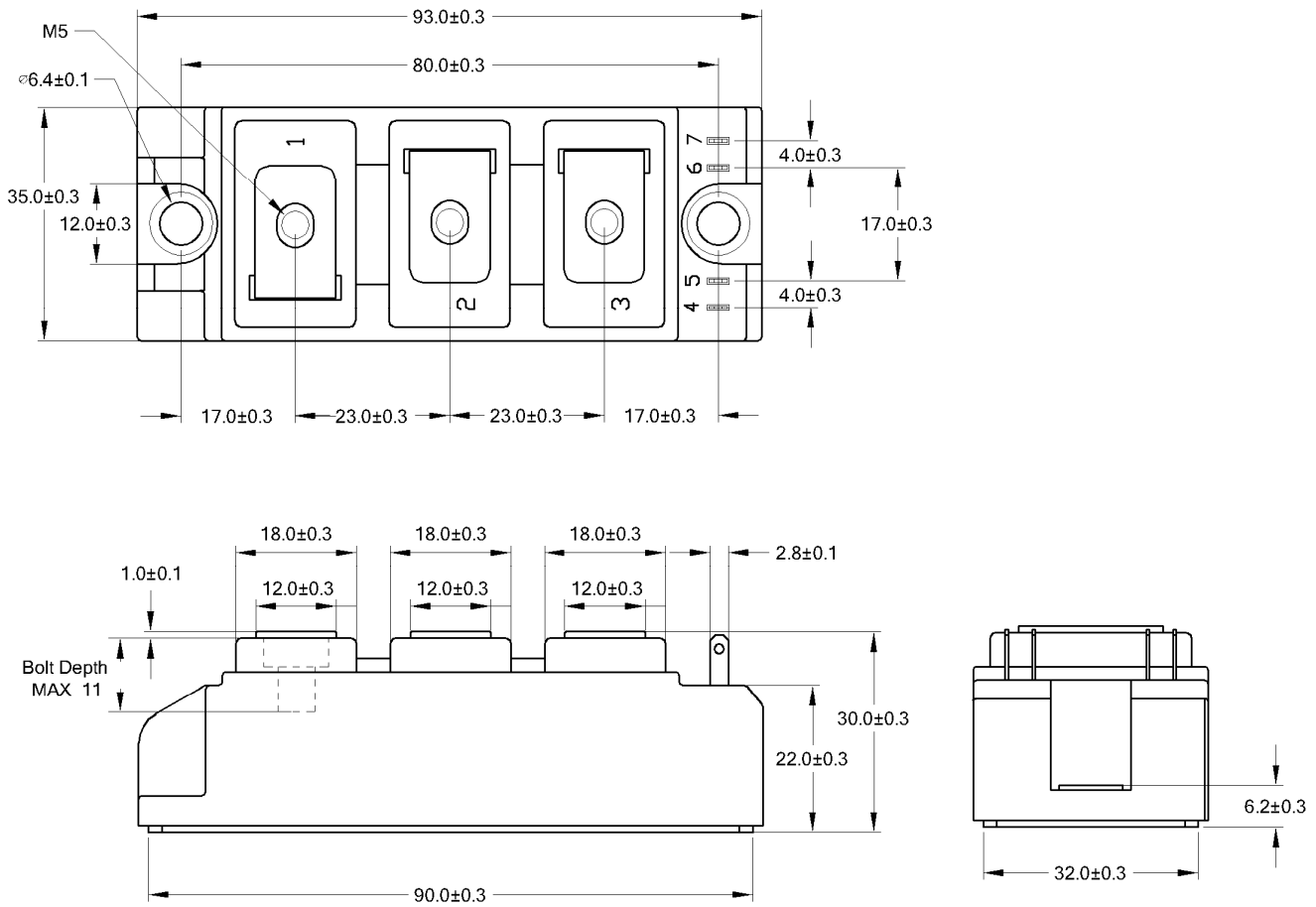
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PRELIMINARY

PACKAGE OUTLINES



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